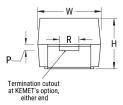


T525Y477M006AHE035

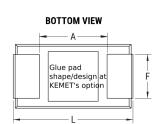
T525, Tantalum, Polymer Tantalum, 470 uF, 20%, 6.3 VDC, SMD, Polymer, Molded, Low ESR, Non-Combustible, 35 mOhms, 7343, 4mm

CATHODE (-) END VIEW









Click here for the 3D model.

Footprint 7343 L 7.3mm +/-0.3mm W 4.3mm +/-0.3mm H 3.8mm +/-0.2mm T 0.13mm REF S 1.3mm +/-0.3mm F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF X 0.1mm +/-0.1mm	Dimensions	
W 4.3mm +/-0.3mm H 3.8mm +/-0.2mm T 0.13mm REF S 1.3mm +/-0.3mm F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	Footprint	7343
H 3.8mm +/-0.2mm T 0.13mm REF S 1.3mm +/-0.3mm F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	L	7.3mm +/-0.3mm
T 0.13mm REF S 1.3mm +/-0.3mm F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	W	4.3mm +/-0.3mm
S 1.3mm +/-0.3mm F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	Н	3.8mm +/-0.2mm
F 2.4mm +/-0.1mm A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	Т	0.13mm REF
A 3.8mm MIN B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	S	1.3mm +/-0.3mm
B 0.5mm +/-0.15mm P 1.7mm REF R 1mm REF	F	2.4mm +/-0.1mm
P 1.7mm REF R 1mm REF	А	3.8mm MIN
R 1mm REF	В	0.5mm +/-0.15mm
	Ρ	1.7mm REF
X 0.1mm +/-0.1mm	R	1mm REF
	Х	0.1mm +/-0.1mm

Т

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information	
Series	T525
Dielectric	Polymer Tantalum
Style	SMD Chip
Description	SMD, Polymer, Molded, Low ESR, Non- Combustible
Features	Low ESR
RoHS	No
Prop 65	A WARNING: Cancer and reproductive harm - http://www.p65warnings.ca.gov.
SCIP Number	b064b03e-bd75-42af-b342-1fe94dec2340
Termination	Tin Lead (SnPb)
AEC-Q200	No
Typical Component Weight	493.99 mg
Shelf Life	52 Weeks
MSL	3

Specifications	
Capacitance	470 uF
•	470 ur
Capacitance Tolerance	20%
Voltage DC	6.3 VDC (105C), 4.22 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	105°C
Life	2000 Hrs (125C)
Humidity	60C, 90% RH, 1000 Hours, No Load
Dissipation Factor	10% 120Hz 25C
Failure Rate	N/A
ESR	35 mOhms (100kHz 25C)
Ripple Current	2600 mA (rms, 100kHz 45C), 1820 mA (rms, 85C), 650 mA (rms, 125C)
Leakage Current	296.1 uA (5min 25°C)

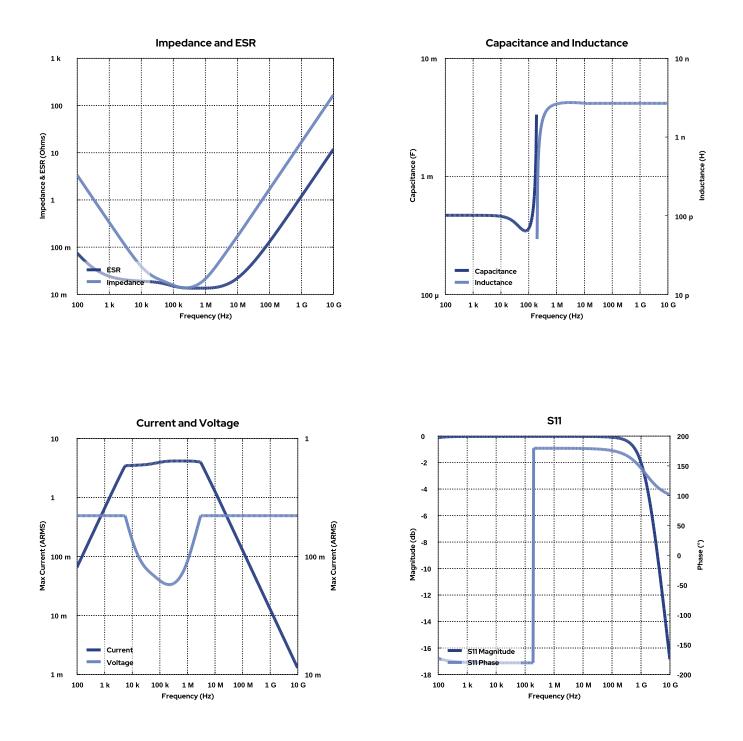
Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.



T525Y477M006AHE035 T525, Tantalum, Polymer Tantalum, 470 uF, 20%, 6.3 VDC, SMD, Polymer, Molded, Low ESR, Non-Combustible, 35 mOhms, 7343, 4mm

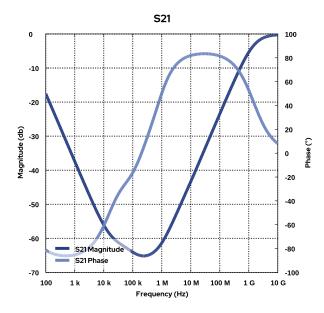
Simulations

For the complete simulation environment please visit K-SIM.





T525Y477M006AHE035 T525, Tantalum, Polymer Tantalum, 470 uF, 20%, 6.3 VDC, SMD, Polymer, Molded, Low ESR, Non-Combustible, 35 mOhms, 7343, 4mm





T525Y477M006AHE035

T525, Tantalum, Polymer Tantalum, 470 uF, 20%, 6.3 VDC, SMD, Polymer, Molded, Low ESR, Non-Combustible, 35 mOhms, 7343, 4mm

These are simulations.

This is not a specification!

The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

The responses shown do not represent a specified or implied maximum capability of the device for all applications.

- The ESR used for ripple "Ripple Current/Voltage vs. Frequency" plots is the ESR at ambient temperature.
- The ESR in the "Temperature Rise vs. Ripple Current" plots is adjusted to each incremental temperature rise before the power and ripple current is calculated.
- The effects shown herein are based on measured data from a multiple part sample of the parts in question.
- Ripple capability of this device will be factored by thermal resistance (Rth) created by circuit traces (addi affects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance. The peak voltages generated in the "Temperature Rise vs. Combined Ripple Currents" plot are calculated for each frequency and are not combined with voltages generated at any other
- harmonics.
- Please consult with the catalog or field applications engineer for maximum capability of the device in specific applications.

All product information and data (collectively, the "Information") are subject to change without notice.

KEMET K-SIM is designed to simulate behavior of components with respect to frequency, ambient temperature, and DC bias levels. The responses shown represent the typical response for each part type. Specific responses may vary, depending on manufacturing variation effects of all parameters involved, including the specified tolerances applied to capacitance and unspecified variations of ESR, ESL, and leakage resistance.

All Information given herein is believed to be accurate and reliable, but is presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute – and we specifically disclaim – any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.

If you have any questions please contact K-SIM.